TOSHIBA Transistor Silicon NPN Triple Diffused Mesa Type

# 2SC5695

Horizontal Deflection Output for High Resolution Display, Color TV

• High voltage: V<sub>CBO</sub> = 1500 V

• Low saturation voltage:  $V_{CE (sat)} = 3 V (max)$ 

• High speed:  $t_f(2) = 0.1 \mu s$  (typ.)

## Maximum Ratings (Tc = 25°C)

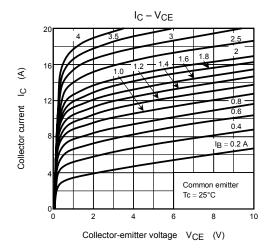
Characteristics		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	1500	V	
Collector-emitter voltage		V <sub>CEO</sub>	700	V	
Emitter-base voltage		V <sub>EBO</sub>	5	٧	
Collector current	DC	Ic	22	А	
	Pulse	I <sub>CP</sub>	44		
Base current		Ι <sub>Β</sub>	11	Α	
Collector power dissipation		PC	200	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

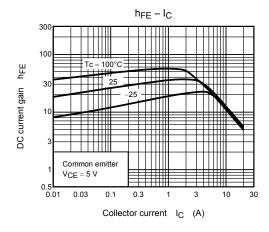
# 20.5MAX. 83.3±0.2 20.5MAX. 83.3±0.2 20.5MAX. 83.3±0.2 20.5MAX. 83.3±0.2 00.7 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 1.5 2.5 3.0 3.0 3.5 45±0.15 5.45±0

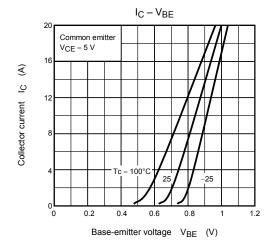
Weight: 9.75 g (typ.)

## **Electrical Characteristics (Tc = 25°C)**

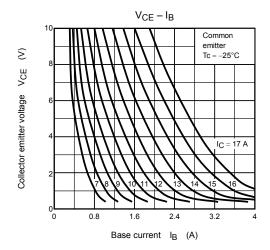
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB} = 1500 \text{ V}, I_E = 0$	_	_	1	mA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	10	μА
Collector-emitter breakdown voltage		V <sub>(BR)</sub> CEO	$I_C = 10 \text{ mA}, I_B = 0$	700	_	_	V
DC current gain		h <sub>FE</sub> (1)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 2 A	20	_	50	_
		h <sub>FE</sub> (2)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 A	8	_	17	
		h <sub>FE</sub> (3)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 17 A	4.8	_	8.3	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 17 A, I <sub>B</sub> = 4.25 A	_	_	3	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 17 A, I <sub>B</sub> = 4.25 A	_	1.0	1.5	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 0.1 A	_	2	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	280	_	pF
Switching time	Storage time	t <sub>stg</sub> (1)	I <sub>CP</sub> = 8 A, I <sub>B1 (end)</sub> = 1.4 A, f <sub>H</sub> = 64 kHz	_	2.5	3	μs
	Fall time	t <sub>f</sub> (1)	$f_H = 64 \text{ kHz}$	_	0.15	0.3	
	Storage time	t <sub>stg</sub> (2)	I <sub>CP</sub> = 8 A, I <sub>B1 (end)</sub> = 1.1 A,		1.6	1.8	
	Fall time	t <sub>f</sub> (2)	$I_{CP} = 8 \text{ A, } I_{B1 \text{ (end)}} = 1.1 \text{ A,} $ $f_{H} = 100 \text{ kHz}$	_	0.1	0.15	

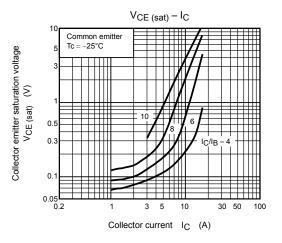


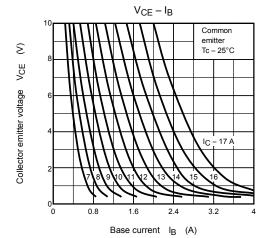


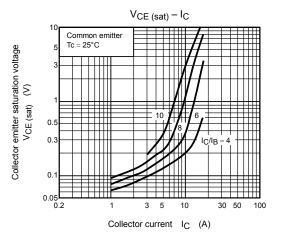


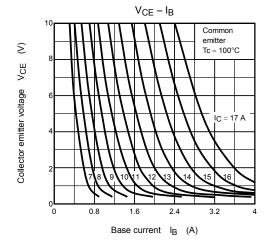
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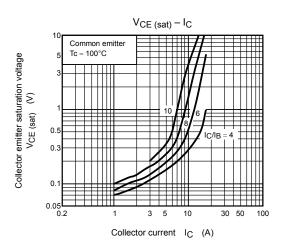




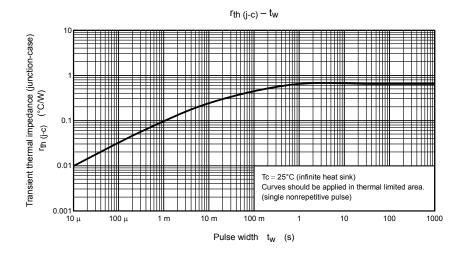


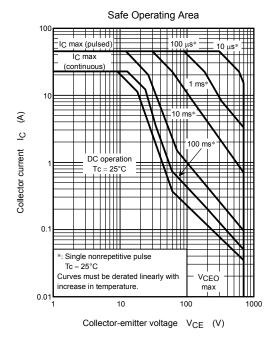


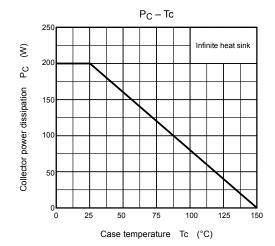




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